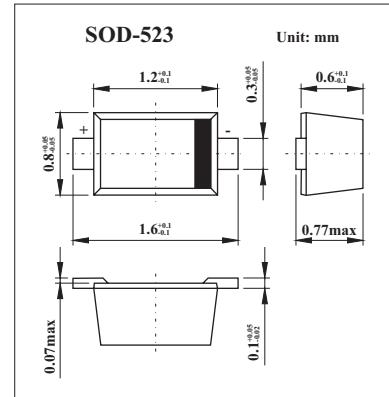


■ Features

- Low capacitance.(C=1.0pF max)
- Low forward resistance. ($r_f=0.7 \Omega$ max)



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Value	Unit
Reverse voltage	V_R	30	V
Power dissipation	P_d	150	mW
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse voltage	V_R	$I_R = 1 \mu\text{A}$	30			V
Reverse current	I_R	$V_R = 25 \text{ V}$			100	nA
Forward voltage		$I_F = 2 \text{ mA}$			0.85	V
Capacitance	C_1	$V_R = 1 \text{ V}, f = 1 \text{ MHz}$			1.0	pF
	C_6	$V_R = 6 \text{ V}, f = 2 \text{ MHz}$			0.9	
Forward resistance	r_f	$I_F = 2 \text{ mA}, f = 100 \text{ MHz}$		0.55	0.7	Ω

■ Marking

Marking	P3
---------	----